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冀雅(廊坊)电子股份有限公司 JIYA(LANGFANG) ELECTRONICS CO., LTD

模块产品规格书 SPECIFICATION FOR LCD MODULE

产品型号 Product model	JYG-17626401G(R)-VA(JY25A09)			
拟制	审核	批准		
Prepared by	Checked by	Approved by		
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客户名称		
Client name		
客户型号		
Client model		
客户	确认/Approved sig	nature
采购/日期	品质/日期	研发/日期
PUR/Date	QC/Date	R&D/Date

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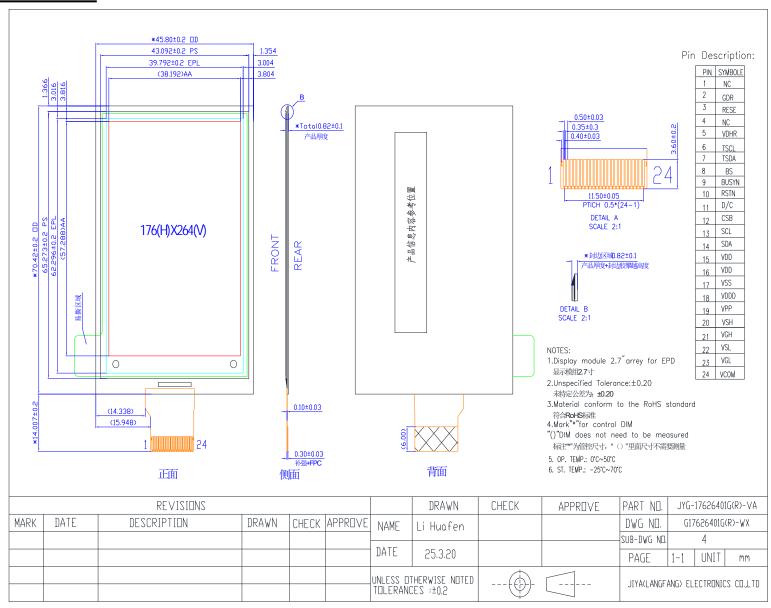
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1.LCM DRAWING



2. GENERAL DESCRIPTION

ITEM	CONTENT	UNIT
DISPLAY TYPE	EPD	
OPEATING	0°C-+50°C	$^{\circ}$
TEMPERATURE		
STORAGE	-25°C-+70°C	$^{\circ}$
TEMPERATURE		
INTERFACE TYPE	SPI	
MODULE	45.8(w)*70.42(h)*0.82(D)	mm
DIMENSION		
ACTIVE AREA	38.192(w)*57.288(h)	mm
Pixel Pitch	$0.217(w) \times 0.217(h)$	

3. ELECTRO-OPTICAL CHARACTERISTICS

Measurements are made with that the illumination is under an angle of 45 degrees, the detection is perpendicular unless otherwise specified.

Crowbal	Danamatan	Parameter Conditions		Values			Notes	
Symbol	Farameter	Conditions	Min.	Тур.	Max	Units	Notes	
R	White Reflectivity	White	45	48	-	%	3-1	
CR	Contrast Ratio		20:1	25:1	-	-	3-2	
т	Full refresh	at 25 °C	500	750	-	ms	3-3	
T_{update}	Partial refresh	at 25 °C	-	250	-	ms	3-3	

Notes: 3-1. Luminance meter: Eye-One Pro Spectrophotometer.

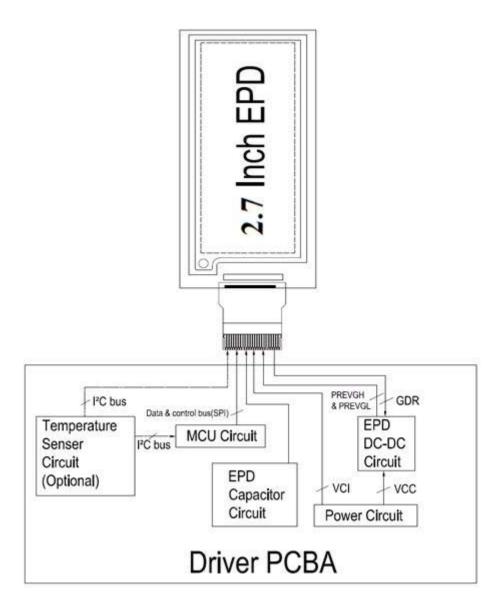
3-2. CR=Surface Reflectance with all white pixel/Surface Reflectance with all black pixels.

3-3. Waveform provided by OED is required.

Full refresh: The screen will flicker several times during the refresh process.

Partial refresh: The screen does not flicker during the refresh process.

4. BLOCK DIAGRAM



5. PINS DESCRIPTION

No.	Name	I/O	Description	Remark
1	NC		Do not connect with other NC pins	
2	GDR	О	N-Channel MOSFET Gate Drive Control	
3	RESE	I	Current Sense Input for the Control Loop	
4	NC		Do not connect with other NC pins	
5	VDHR	С	Positive Source driving voltage 1	
6	TSCL	О	I ² C Interface to digital temperature sensor Clock pin	
7	TSDA	I/O	I ² C Interface to digital temperature sensor Data pin	
8	BS	I	Bus Interface selection pin	Note 5-4
9	BUSYN	0	Busy state output pin	Note 5-3
10	RSTN	I	Reset signal input. Active Low.	
11	D/C	I	Data /Command control pin	Note 5-2
12	CSB	I	Chip select input pin	Note 5-1
13	SCL	I	Serial Clock pin (SPI)	
14	SDA	I	Serial Data pin (SPI)	
15	VDD	P	Power Supply for interface logic pins	
16	VDD	P	Power Supply for the chip	
17	VSS	P	Ground	
18	VDDD	С	Core logic power pin VDDD can be regulated internally from VDD. A capacitor should be connected between VDDD and VSS under all circumstances	
19	VPP	P	Power Supply for OTP Programming	
20	VSH	С	Positive Source driving voltage 2	
21	VGH	С	Positive Gate driving voltage	
22	VSL	С	Negative Source driving voltage	
23	VGL	С	Negative Gate driving voltage	
24	VCOM	С	VCOM driving voltage	

I = Input Pin, O =Output Pin, I/O = Bi-directional Pin (Input/Output), P = Power Pin, C = Capacitor Pin

- Note 5-1: This pin is the chip select input connecting to the MCU. The chip is enabled for MCU communication only when CSB is pulled LOW.
- Note 5-2: This pin is Data/Command control pin connecting to the MCU in 4-wire SPI mode. When the pin is pulled HIGH, the data at D1 will be interpreted as data. When the pin is pulled LOW, the data at D1 will be interpreted as command.
- Note 5-3: This pin is Busy state output pin. When Busy is High, the operation of chip should not be interrupted, command should not be sent, e.g., The chip would put Busy pin High when
 - Outputting display waveform
 - Programming with OTP
 - Communicating with digital temperature sensor

Note 5-4: Bus interface selection pin

BS State	MCU Interface
L	4-lines serial peripheral interface(SPI)
Н	3- lines serial peripheral interface(SPI) - 9 bits SPI

6.ELECTRONIC CHARACTERISTICS

6.1 Absolute Maximum Rating

Parameter	Symbol	Symbol Rating	
Logic supply voltage	V_{dd}	-0.5 to +4.0	V
Logic Input voltage	V_{IN}	-0.5 to V _{dd} +0.5	V
Logic Output voltage	V_{OUT}	-0.5 to V_{dd} +0.5	V

Note: Maximum ratings are those values beyond which damages to the device may occur. Functional operation should be restricted to the limits in the Panel DC Characteristics tables.

6.2. Panel DC Characteristics

The following specifications apply for: VSS=0V, VDD=3.0V, T_{OPR} =25°C.

Parameter	Symbol	Condition	Applicable pin	Min.	Тур.	Max.	Unit
Logic supply voltage	V_{dd}	-	VDD	2.2	3.0	3.6	V
High level input voltage	V_{IH}	-	-	$0.8~\mathrm{V_{dd}}$	-	-	V
Low level input voltage	V_{IL}	-	-	-	-	$0.2~\mathrm{V_{dd}}$	V
High level output voltage	V _{OH}	IOH = -100uA	-	0.9 V _{dd}	-	-	V
Low level output voltage	V _{OL}	IOL = 100uA	-	-	-	$0.1~\mathrm{V_{dd}}$	V
OTP Program voltage	V_{pp}	-	VPP	-	7.5	-	V
Typical power panel	P _{TYP}	-	-	-	12	45	mW
Deep sleep mode	P _{STPY}	-	-	-	3	-	uW
Typical operating current	Iopr_VDD	$V_{dd} = 3.0V$ -	-	-	4.0	15	mA
Sleep mode current	Islp_VDD	VDD=3.0V DC/DC OFF No clock No output load Ram data retain	VDD	-	20		uA
Deep sleep mode current	IdslpVDD	VDD=3.0V DC/DC OFF No clock No output load Ram data not retain	VDD	-	1		uA
Operation temperature range	T_{OPR}	-	-	0	-	50	°C
Operation relative humidity	RHop	-	-	-	-	70	%RH
Operation illuminance intensity	Е	indoor only	-	-	-	2000	lux
Storage temperature range	T_{STG}	-	-	0	-	50	°C
Storage relative humidity	RHst	-	-	30	-	60	%RH

Notes: 1. The typical power is measured with following transition: from horizontal 2 gray scale pattern to vertical 2 gray scale pattern. (Figure 6-2)

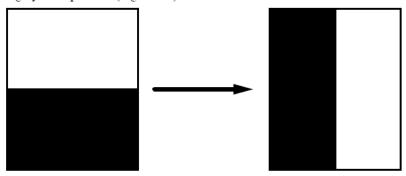


Figure 6-2 The typical power consumption measure pattern

- 2. The deep sleep power is the consumed power when the panel controller is in deep sleep mode.
- The listed electrical/optical characteristics are only guaranteed under the controller & waveform provided by OED.

6.3 Panel DC Characteristics(Driver IC Internal Regulators)

The following specifications apply for: VSS=0V, VDD =3.0V, T_{OPR} =25°C.

Parameter	Symbol	Condition	Applicable pin	Min.	Typ.	Max.	Unit
VCOM output voltage	VCOM	-	VCOM	1	-1.0	-	V

6.4 Panel AC Characteristics

6.4.1 MCU Interface Selection

MCU interface consist of 2 data/command pins and 3 control pins. The pin assignment at different interface mode is summarized in Table 6-4-1. Different MCU mode can be set by hardware selection on BS pins. The display panel only supports 4-wire SPI or 3-wire SPI interface mode.

Pin Name	Data/Connn	and Interface		Control Signal	
Bus interface	SDA	SCL	CSB	D/C	RSTN
4-wire SPI	SDIN	SCLK	CSB	D/C	RSTN
3-wire SPI	SDIN	SCLK	CSB	L	RSTN

Table 6-4-1: MCU interface assignment under different bus interface mode

6.4.2 MCU Serial Interface (4-wire SPI)

The serial interface consists of serial clock SCLK, serial data SDIN, D/C, CSB. In 4-wire SPI mode, SCL acts as SCLK, SDA acts as SDIN.

Function	CSB	D/C	SCLK
Write command	L	L	1
Write data	L	H	1

Note: 1 stands for rising edge of signal

Table6-4-2: Control pins of 4-wire Serial interface

SDIN is shifted into an 8-bit shift register on every rising edge of SCLK in the order of D7, D6, ... D0. D/C is sampled on every eighth clock and the data byte in the shift register is written to the Graphic Display Data RAM (RAM) or command register in the same clock.

Under serial mode, only write operations are allowed.

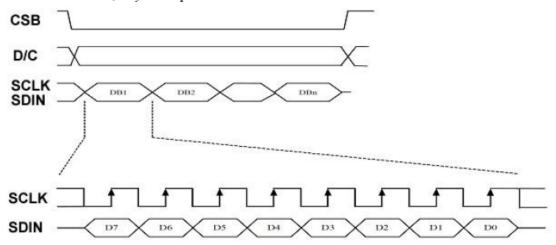


Figure 6-4-2: Write procedure in 4-wire SPI mode

6.4.3 MCU Serial Interface (3-wire SPI)

The 3-wire serial interface consists of serial clock SCLK, serial data SDIN and CSB. In 3-wire SPI mode, SCL acts as SCLK, SDA acts as SDIN.

The operation is similar to 4-wire serial interface while D/C pin is not used. There are altogether 9-bits will be shifted into the shift register on every ninth clock in sequence: D/C bit, D7 to D0 bit. The D/C bit (first bit of the sequential data) will determine the following data byte in the shift register is written to the Display Data RAM (D/C bit = 1) or the command register (D/C bit = 0).

Under serial mode, only write operations are allowed.

Function	CSB	D/C	SCLK
Write command	L	Tie	1
Write data	L	Tie	1

Note:

stands for rising edge of signal

Table 6-4-3: Control pins of 3-wire Serial interface

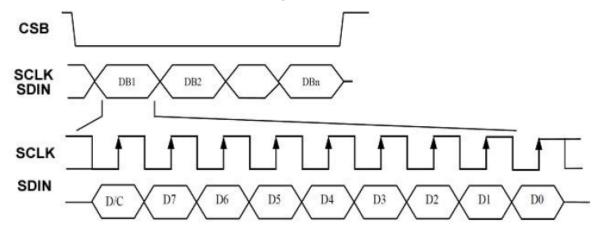
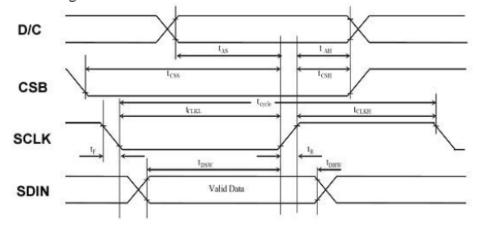


Figure 6-4-3: Write procedure in 3-wire SPI mode

6.4.4 Interface Timing



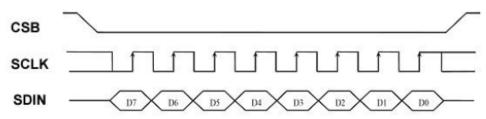


Figure 6-4-4: Serial interface characteristics

 $(V_{dd}$ - VSS = 2.4V to 3.3V, T_{OPR} = 25°C, CL =20pF)

Symbol	Parameter	Min.	Typ.	Max.	Unit
t _{cycle}	Clock Cycle Time	250	-	-	ns
t _{AS}	Address Setup Time	150	-	-	ns
t _{AH}	Address Hold Time	150	-	-	ns
t _{CSS}	Chip Select Setup Time	120	-	-	ns
t _{CSH}	Chip Select Hold Time	60	-	-	ns
t _{DSW}	Write Data Setup Time	50	-	-	ns
t _{DHW}	Write Data Hold Time	15	-	-	ns
t _{CLKL}	Clock Low Time	100	-	-	ns
t _{CLKH}	Clock High Time	100	-	-	ns
t _R	Rise Time [20% ~ 80%]	-	15		ns
t _F	Fall Time [20% ~80%]	-	-	15	ns

Table 6-4-4: Serial Interface Timing Characteristics

7. INSTRUCTION DESCRIPTION

NC

8. PRODUCT QUALITY & RELIABILITY

- 8.1 Appearances Inspection Standard
 - 8.1.1 Appearances Specification

This appearance inspection shall be applied to segment EPD modules.

8.1.2 Inspection Conditions

Viewing Angle: $\alpha = \pm 45^{\circ}$

Viewing Distance: 30cm±10cm

Ambient Luminance: 700~1000 Lux.

Supply Voltage: Typical value described on the Electrical Characteristics

Environment Ambient Temperature: 20 °C~25 °C

Environment Ambient Humidity: 40~70%RH

ESD should be controlled within ±200V

8.1.3 Inspection Level: Level II

Sampling table: GB/T 2828.1-2012 II, unless otherwise agreed in writing.

8.1.4 Acceptance Quality Level (AQL)

Major Defect: 0.65, Minor Defect: 1.5

8.1.5 Classification of Defects

Defects are classified as either a major or a minor defect defined as below.

Major Defect :It is a defect that is likely to result in failure or to reduce materially the usability of the product for the intended function.

Minor Defect :It is a defect that will not result in functioning problem with deviation classified.

- 8.2 Quality Criteria
 - 8.2.1 Zone Definitions

A Zone: EPD Active Area (not including border)

B Zone: Out of Active Area

8.2.2 Appearances Criteria

As shown in the tables below. If any other items, standard values or applicable zones are required to be defined, a written agreement shall be signed, and otherwise a limited sample shall be made for reference.

Major Defects:

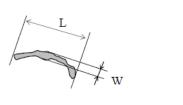
Item	Description	Classification				
No Display	No display shown on screen due to malfunction	Major				
Line Missing	Line missing	Major				
Abnormal Display	Unusual pattern or function displayed	Major				
TFT Broken	TFT broken by external force	Major				

Minor Defects:

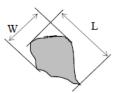
Item		Chitania	Specific Zone	
Name	Description	Criteria	A Zone	B Zone
Dot defect	Spot/ Air bubble/ Foreign material in dot shape	D≤0.30mm	Ignore	
		0.30mm <d≤0.50mm< td=""><td colspan="2">≤5 Ignore</td></d≤0.50mm<>	≤5 Ignore	
		D>0.50mm	0	
Line defect	Scratch on top surface/ Foreign material in line or spiral shape	$L{\leqslant}1.0~mm$, $W{\leqslant}0.15mm$	Ignore	
		1.0mm <l≤5.0mm &<br="">0.15mm<w≤0.5mm< td=""><td>≤4</td><td>Ignore</td></w≤0.5mm<></l≤5.0mm>	≤4	Ignore
		L>5.0mm or W>0.5mm	0	
Chipping	Corner chip	Not affect the display, not have diffuse or comm		d ara alsa
	Edge chip	Not affect the display, not have diffuse of	or communitied cracks	
Curl	Curl for Panel	≤1.0 mm		

Remarks:

Definitions of "line" and "dot":



a. Line

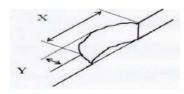


b. Dot

When L \leq 0.5mm or L \leq 4W, defined as a dot. Definitions of "Chipping":



c. Corner chip



d. Edge chip

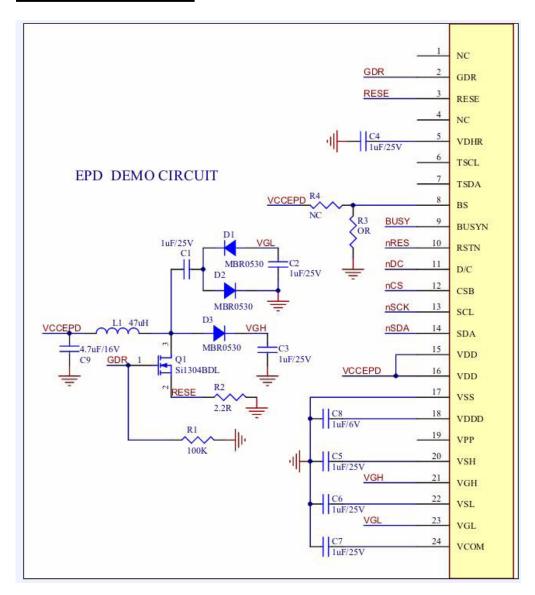
$\pmb{8.3}\underline{\textbf{RELIABILITY}}$

No.	Test	Condition	Method	Remark
1	High- Temperature Operation	T = +50°C, RH = 30% for 240 hrs	IEC 60 068-2-2Bp	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
2	Low- Temperature Operation	T = 0°C for 240 hrs	IEC 60 068-2-2Ab	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
3	High- Temperature Storage	T = +70°C, RH=23% for 240 hrs	IEC 60 068-2-2Bp	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
4	Low- Temperature Storage	T = -25°C for 240 hrs	IEC 60 068-2-1Ab	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
5	High- Temperature, High- Humidity Operation	T = +40°C, RH = 90% for 168 hrs	IEC 60 068-2-3CA	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
6	High Temperature, High- Humidity Storage	T = +60°C, RH=80% for 240hrs	IEC 60 068-2-3CA	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
7	Thermal Shock	1 cycle:[-25°C 30min]→[+70 °C 30 min] : 100 cycles	IEC 60 068-2-14	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
8	Package Vibration	1.04G, Frequency: 10~500Hz Direction: X,Y,Z Duration: 1 hours in each direction	Full packed for shipment	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
9	Package Drop Impact	Drop from height of 122 cm on concrete surface. Drop sequence: 1 corner, 3edges, 6 faces One drop for each	Full packed for shipment	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.
10	Electrostatic Effect (non- operating)	Machine model +/- 250V, 0Ω, 200pF	IEC 62179, IEC 62180	At the end of the test, electrical, mechanical, and optical specifications shall be satisfied.

9.PRECAUTIONS IN USING

- The EPD Panel / Module is manufactured from fragile materials such as glass and plastic, and may be broken or cracked if dropped. Please handle with care. Do not apply force such as bending or twisting to the EPD panel
- The display module should not be exposed to harmful gases, such as acid and alkali gases, which corrode electronic components.
- 3. Do not apply pressure to the EPD panel in order to prevent damaging it
- 4. Do not connect or disconnect the interface connector while the EPD panel is in operation
- 5. Do not stack the EPD panels / Modules.
- Keep the EPD Panel / Module in the specified environment and original packing boxes when storage in order to avoid scratching and keep original performance.
- 7. Do not disassemble or reassemble the EPD panel
- 8. Use a soft dry cloth without chemicals for cleaning. Please don't press hard for cleaning because the surface of the protection sheet film is very soft and without hard coating. This behavior would make dent or scratch on protection sheet
- Please be mindful of moisture to avoid its penetration into the EPD panel, which may cause damage during operation
- 10. It's low temperature operation product. Please be mindful the temperature different to make frost or dew on the surface of EPD panel. Moisture may penetrate into the EPD panel because of frost or dew on surface of EPD panel, and makes EPD panel damage.
- 11. High temperature, high humidity, sunlight or fluorescent light may degrade the EPD panel's performance. Please do not expose the unprotected EPD panel to high temperature, high humidity, sunlight, or fluorescent for long periods of time. Please store the EPD panel in controllable environment of warehouse and original package. Without sunlight, without condensation a temperature range of 15°C to 35°C, and humidity from 30%RH to 60%RH.

10. APPLICATION

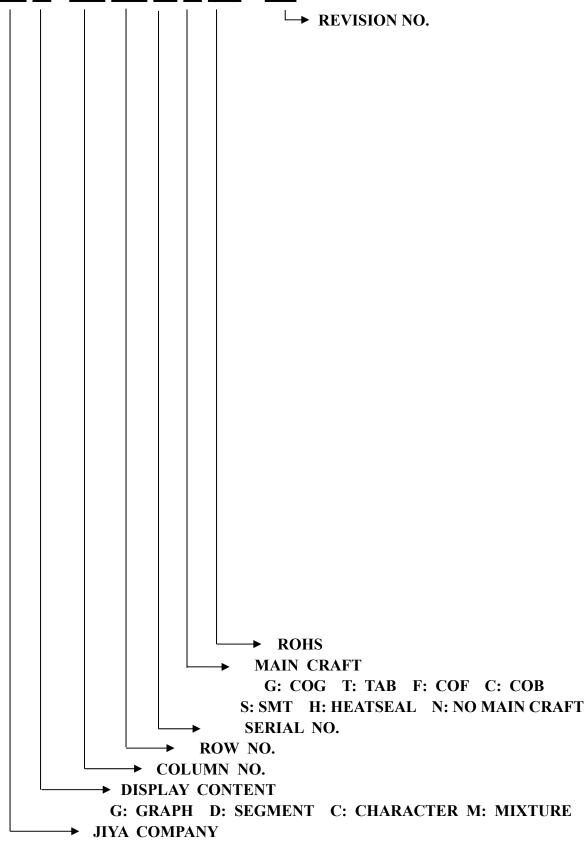


References for component selection as below:

References for component selection as below:				
Components	Value/Type	Requirements		
C1-C8	1uF	Dielectric: X5R/X7R, Rated Voltage: 25V		
C9	4.7uF	Dielectric: X5R/X7R, Rated Voltage: 25V		
	diode	MBR0530		
D1-D3		1.reverse DC≥30V		
D1 - D3		2.Io≥500mA		
		3.Forward≤430mV		
R1	100ΚΩ	1%		
R2	2.2Ω	1%		
		Si1304BDL		
01	NMOS	1.Drain Source breakdown voltage≥30V		
Q1		2.Vgs(Vth)=0.9V (TYP) ,1.3V(Max)		
		3. Rds on≤2.1Ω @Vgs=2.5V		
L1	47uH	CDRH2D18/LDNP-470NC		
LI	4/111	Io=500(Max)		

11. CLASSIFICATION INFORMATION

<u>JY G –176 264 01 G (R) – VA</u>



12. HISTORY OF VERSION

REVISIONS						
No.	DATE	MARK	DESCRIPTION	ORGANIZED BY	CHECKED BY	APPROVED BY
1						
2						
3						
4						
5						
6						
7						
8						
9						
10						
11						
12						